SMP3003

P-Channel Power MOSFET -75V, -100A, 8.0mΩ, TO-263-2L/TO-263



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Features

• ON-resistance RDS(on)1=6.2m Ω (typ.)

• Input capacitance Ciss=13400pF (typ.)

Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------------|------------------|------------------------|-------------|------|
| Drain to Source Voltage | V _{DSS} | | -75 | V |
| Gate to Source Voltage | VGSS | | ±20 | V |
| Drain Current (DC) | ID | | -100 | А |
| Drain Current (Pulse) | IDP | PW≤10μs, duty cycle≤1% | -400 | А |
| Allowable Power Dissipation | PD | Tc=25°C | 90 | W |
| Channel Temperature | Tch | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |
| Avalanche Energy (Single Pulse) *1 | EAS | | 468 | mJ |
| Avalanche Current *2 | I _{AV} | | -60 | Α |

· 4V drive

Note: *1 V_{DD} =-48V, L=100 μ H, I_{AV} =-60A (Fig.1)

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

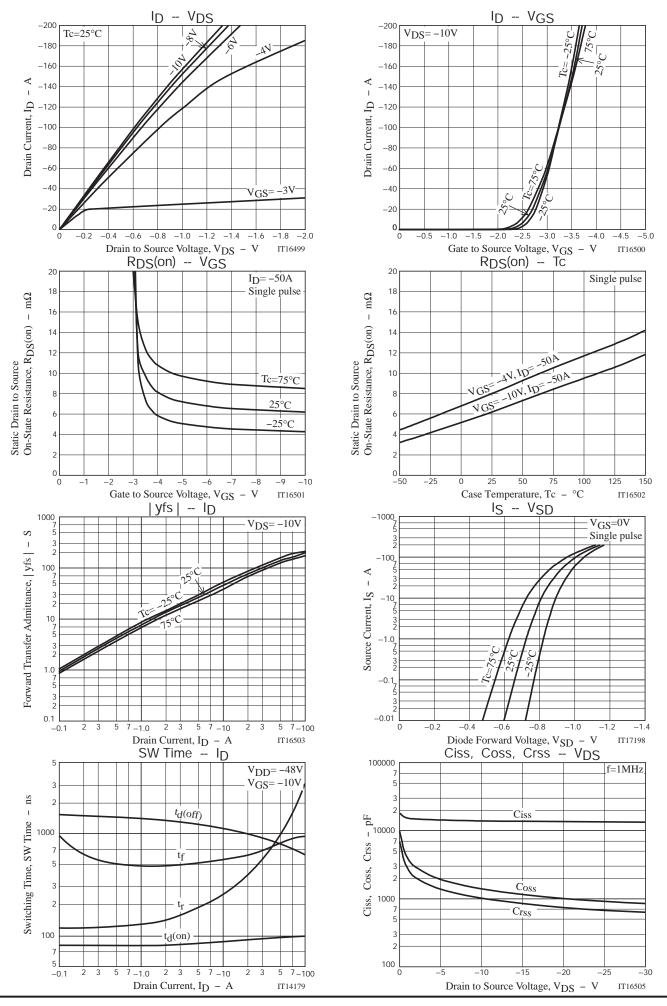
Electrical Characteristics at Ta=25°C

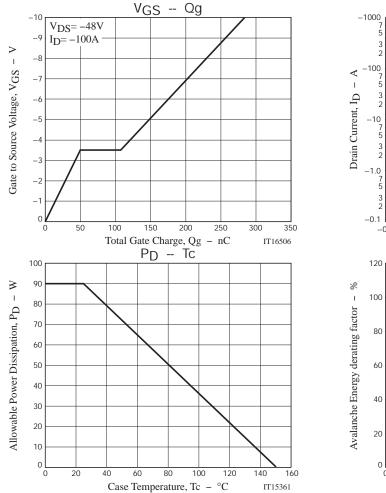
| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|-----------------------|---|---------|-------|------|------|
| | | | min | typ | max | Unit |
| Drain to Source Breakdown Voltage | V(BR)DSS | I _D =-1mA, V _G S=0V | -75 | | | V |
| Zero-Gate Voltage Drain Current | IDSS | V _{DS} =-75V, V _{GS} =0V | | | -10 | μΑ |
| Gate to Source Leakage Current | IGSS | V _{GS} =±16V, V _{DS} =0V | | | ±10 | μΑ |
| Cutoff Voltage | VGS(off) | V _D S=-10V, I _D =-1mA | -1.2 | | -2.6 | V |
| Forward Transfer Admittance | yfs | V _{DS} =-10V, I _D =-50A | | 140 | | S |
| Static Drain to Source On-State Resistance | R _{DS} (on)1 | I _D =-50A, V _G S=-10V | | 6.2 | 8.0 | mΩ |
| | R _{DS} (on)2 | I _D =-50A, V _G S=-4V | | 8.0 | 11 | mΩ |
| Input Capacitance | Ciss | V _{DS} =-20V, f=1MHz | | 13400 | | pF |
| Output Capacitance | Coss | | | 1000 | | pF |
| Reverse Transfer Capacitance | Crss | | | 740 | | pF |
| Turn-ON Delay Time | t _d (on) | See Fig.2 | | 95 | | ns |
| Rise Time | tr | | | 1000 | | ns |
| Turn-OFF Delay Time | t _d (off) | | | 800 | | ns |
| Fall Time | tf | | | 820 | | ns |
| Total Gate Charge | Qg | V _{DS} =-48V, V _{GS} =-10V, I _D =-100A | | 280 | | nC |
| Gate to Source Charge | Qgs | | | 50 | | nC |
| Gate to Drain "Miller" Charge | Qgd | 1 | | 55 | | nC |
| Diode Forward Voltage | V _{SD} | I _S =-100A, V _G S=0V | | -1.0 | -1.5 | V |
| Reverse Recovery Time | t _{rr} | See Fig.3 | | 120 | | ns |
| Reverse Recovery Charge | Qrr | I _S =-100A, V _G S=0V, di/dt=-100A/μs | | 380 | | nC |

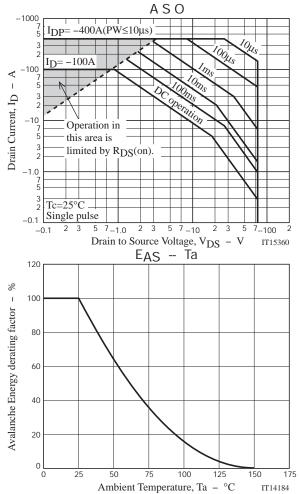
ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

^{*2} L≤100µH, Single pulse







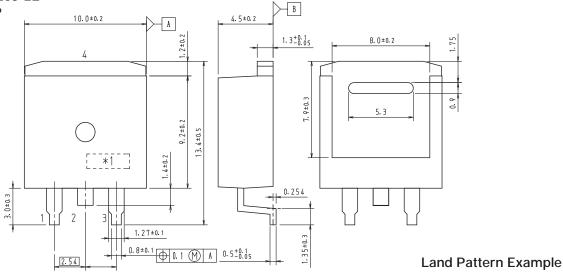
Package Dimensions

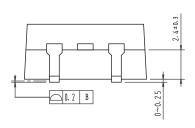
SMP3003-DL-1E

D2PAK/TO-263-2L

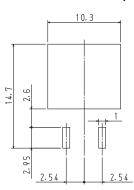
CASE 418AP ISSUE O Unit:mm

- 1: Gate
- 2: Drain
- 3: Source
- 4: Drain



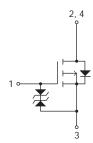


- 1. These dimension do not include mold protrusion
- 2. Pin2 is idle pin with electrical designation only carried
- *1:Lot indication



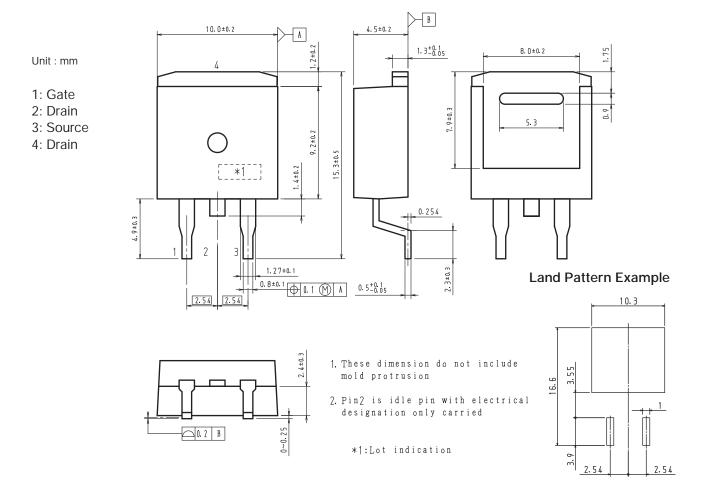
Packing Type: DL

Electrical Connection

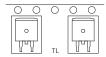


Package Dimensions

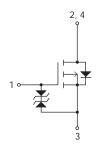
SMP3003-TL-1E



Packing Type: TL



Electrical Connection



Ordering & Package Information

| Device | Package | Shipping | memo | |
|---------------|----------------------------|-----------|---------|--|
| SMP3003-DL-1E | TO-263-2L SC-83, TO-263 | 800 | Db Fron | |
| SMP3003-TL-1E | TO-263 | pcs./reel | Pb-Free | |

Marking



Fig.1 Unclamped Inductive Switching Test Circuit

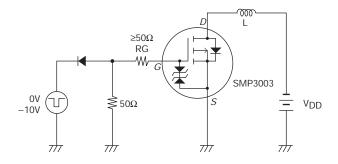


Fig.3 Reverse Recovery Time Test Circuit

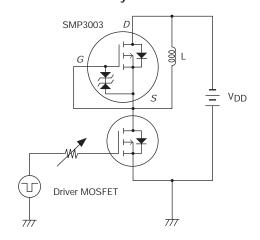
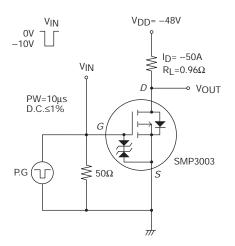


Fig.2 Switching Time Test Circuit



Note on usage: Since the SMP3003 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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